AUTOMOTIVE



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Vishay Siliconix

Automotive N-Channel 40 V (D-S) 175 °C MOSFET



PRODUCT SUMMARY					
V _{DS} (V)	40				
$R_{DS(on)}$ (Ω) at $V_{GS} = 10 \text{ V}$	0.00124				
I _D (A)	350				
Configuration	Single				
Package	PowerPAK SO-8L				

FEATURES

- TrenchFET® Gen IV power MOSFET
- AEC-Q101 qualified
- 100 % R_q and UIS tested
- Q_{gd}/Q_{gs} ratio < 1 optimizes switching characteristics
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912



	Q_D
ı <u>t</u>	
G C F] 1
N-Channel MOSFET	J _s

ABSOLUTE MAXIMUM RATINGS (7	$T_C = 25 ^{\circ}C$, unles	s otherwise noted			
PARAMETER	SYMBOL	LIMIT	UNIT		
Drain-source voltage		V_{DS}	40	V	
Gate-source voltage		V_{GS}	± 20	V	
Continuous drain current	$T_C = 25 ^{\circ}C$	I-	350		
Continuous drain current	T _C = 125 °C	I _D	234		
Continuous source current (diode conduction)		Is	324	Α	
Pulsed drain current ^a		I _{DM}	600		
Single pulse avalanche current		I _{AS}	48		
Single pulse avalanche energy L = 0.1 mH		E _{AS}	115	mJ	
Maximum power dissipation ^a	$T_C = 25 ^{\circ}C$	P_D	500	W	
waximum power dissipation -	T _C = 125 °C	r _D	166	VV	
Operating junction and storage temperature range		T _J , T _{stg}	-55 to +175	°C	
Soldering recommendations (peak temperature) ^c			260	C	

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-ambient	PCB mount b	R_{thJA}	68	°C/W
Junction-to-case (drain)		R_{thJC}	0.3	C/VV

Notes

- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%$
- b. When mounted on 1" square PCB (FR4 material)
- c. See solder profile (www.vishay.com/doc?73257). The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection



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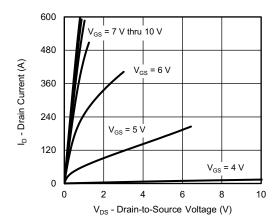
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
Static				l		_	
Drain-source breakdown voltage	V _{DS}	V _{GS}	= 0, I _D = 250 μA	40	-	-	V
Gate-source threshold voltage	V _{GS(th)}	V _{DS} =	= V _{GS} , I _D = 250 μA	2.5	3.0	3.5	V
Gate-source leakage	I _{GSS}	V _{DS} =	0 V, V _{GS} = ± 20 V	-	-	± 100	nA
		V _{GS} = 0 V	V _{DS} = 40 V	-	-	1	
Zero gate voltage drain current	I _{DSS}	V _{GS} = 0 V	V _{DS} = 40 V, T _J = 125 °C	-	-	50	μA
-		$V_{GS} = 0 V$	V _{DS} = 40 V, T _J = 175 °C	-	-	250	
On-state drain current ^a	I _{D(on)}	V _{GS} = 10 V	$V_{DS} \ge 5 \text{ V}$	30	-	-	Α
		V _{GS} = 10 V	I _D = 15 A	-	0.00103	0.00124	
Drain-source on-state resistance a	R _{DS(on)}	V _{GS} = 10 V	I _D = 15 A, T _J = 125 °C	-	-	0.00190	Ω
		V _{GS} = 10 V	I _D = 15 A, T _J = 175 °C	-	-	0.00223	
Forward transconductance b	9 _{fs}	V _{DS} = 15 V, I _D = 10 A		-	95	-	S
Dynamic ^b							
Input capacitance	C _{iss}			-	5309	6636	
Output capacitance	C _{oss}	$V_{GS} = 0 V$	$V_{DS} = 25 \text{ V}, f = 1 \text{ MHz}$	-	1521	1902	рF
Reverse transfer capacitance	C _{rss}			-	138	175	
Total gate charge ^c	Qg			-	86	107	
Gate-source charge ^c	Q_{gs}	V _{GS} = 10 V	$V_{DS} = 20 \text{ V}, I_{D} = 40 \text{ A}$	-	23.6	-	nC
Gate-drain charge ^c	Q_{gd}			-	6	-	
Gate resistance	Rg		f = 1 MHz	1	1.65	2.64	Ω
Turn-on delay time ^c	t _{d(on)}			-	18	24	
Rise time ^c	t _r		= 20 V, $R_L = 0.5 \Omega$	-	17	21	ns
Turn-off delay time ^c	t _{d(off)}	$I_D \cong 40 A$,	$V_{GEN} = 10 \text{ V}, R_g = 1 \Omega$	-	35	44	115
Fall time ^c	t _f				13	17	
Source-Drain Diode Ratings and Chara	acteristics ^b						
Pulsed current ^a	I _{SM}			-	-	600	Α
Forward voltage	V_{SD}	I _F = 15 A, V _{GS} = 0 V		-	-	1.1	V
Body diode reverse recovery time	t _{rr}			-	52	68	ns
Body diode reverse recovery charge	Q _{rr}	I _F = 40 A, di/dt = 100 A/μs		-	36	47	nC
Reverse recovery fall time	t _a			-	27	46	ns
Reverse recovery rise time	t _b			-	25	46	
Body diode peak reverse recovery current	I _{RM(REC)}		-	1.3	2.2	Α	

Notes

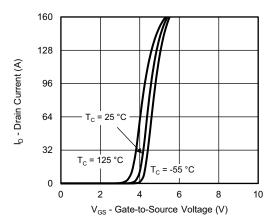
- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%$
- b. Guaranteed by design, not subject to production testing
- c. Independent of operating temperature

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

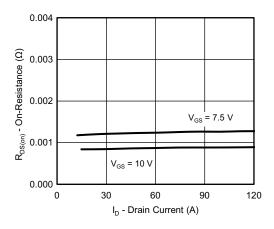




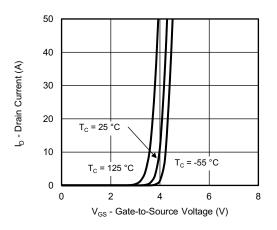
Output Characteristics



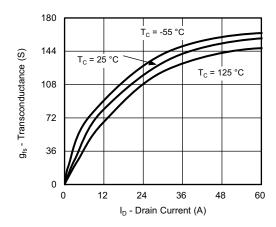
Transfer Characteristics



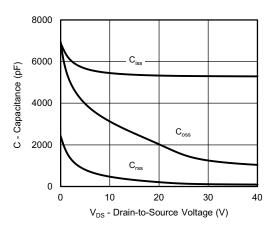
On-Resistance vs. Drain Current



Transfer Characteristics



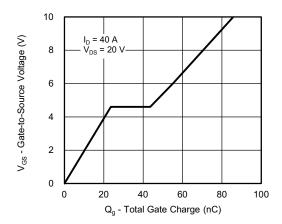
Transconductance



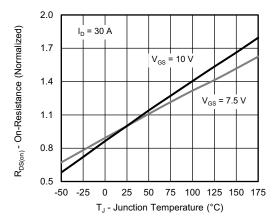
Capacitance

For technical questions, contact: automostechsupport@vishay

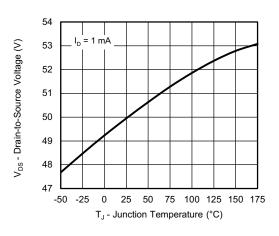




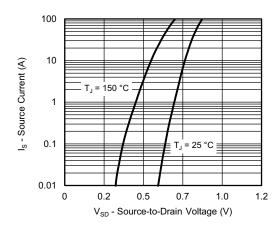
Gate Charge



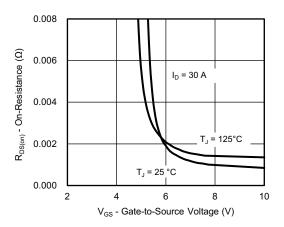
On-Resistance vs. Junction Temperature



Drain Source Breakdown vs. Junction Temperature

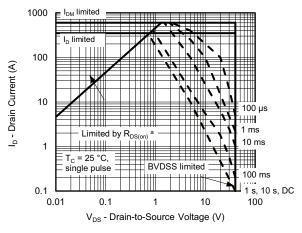


Source Drain Diode Forward Voltage



On-Resistance vs. Gate-to Source Voltage

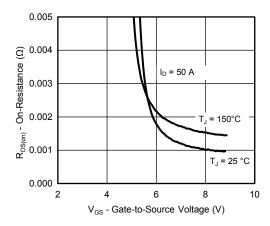




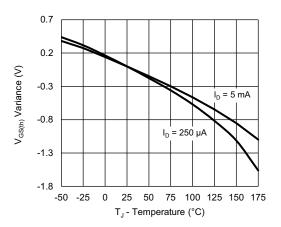
Safe Operating Area

Note

a. $V_{GS} > minimum V_{GS}$ at which $R_{DS(on)}$ is specified

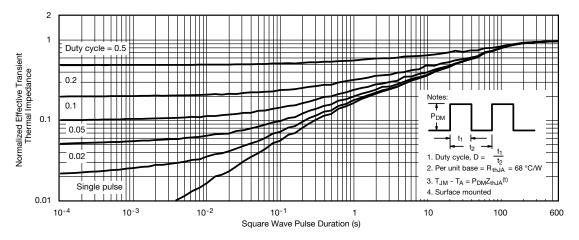


On-Resistance vs. Gate-to Source Voltage

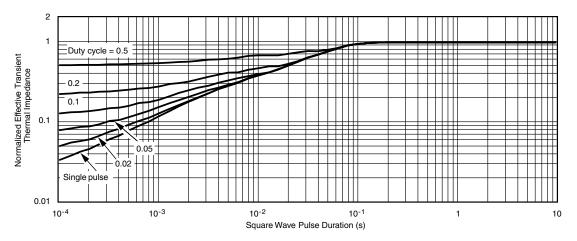


Threshold Voltage





Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case

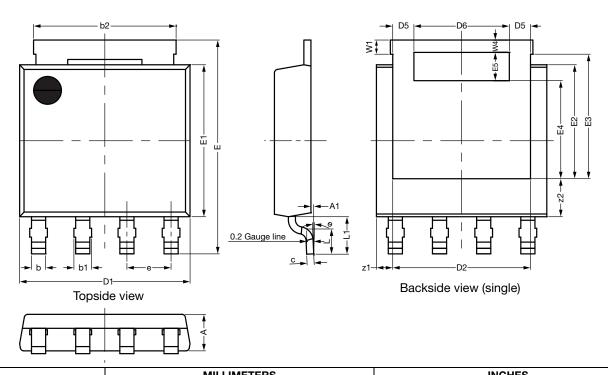
Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction-to-Case (25 °C) are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package / tape drawings, part marking, and reliability data, see www.vishay.com/ppg?76588.

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PowerPAK® SO-8L (PPKSO8LWLA) Case Outline 3



DIM.		MILLIMETERS		INCHES			
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	
Α	1.00	1.05	1.10	0.039	0.041	0.043	
A1	0.00		0.127	0.000		0.005	
b	0.33	0.41	0.49	0.013	0.016	0.019	
b1	0.43	0.51	0.59	0.017	0.020	0.023	
b2	4.00	4.10	4.20	0.157	0.161	0.165	
С	0.15	0.20	0.25	0.006	0.008	0.010	
D1	4.80	4.90	5.00	0.189	0.193	0.197	
D2	3.86	3.96	4.06	0.152	0.156	0.160	
D5	0.51	0.61	0.71	0.020	0.024	0.028	
D6	2.64	2.74	2.84	0.104	0.108	0.112	
е		1.27 BSC		0.050 BSC			
Е	6.05	6.15	6.25	0.238	0.242	0.246	
E1	4.27	4.37	4.47	0.168	0.172	0.176	
E2	3.18	3.28	3.38	0.125	0.129	0.133	
E3	3.48	3.58	3.68	0.137	0.141	0.145	
E4	2.72	2.82	2.92	0.107	0.111	0.115	
E5	0.71	0.81	0.91	0.028	0.032	0.036	
L	0.62	0.72	0.82	0.024	0.028	0.032	
L1	0.92	1.07	1.22	0.036	0.042	0.048	
W1	0.31	0.41	0.51	0.012	0.016	0.020	
W4	0.31	0.36	0.41	0.012	0.014	0.016	
z1	0.37	0.47	0.57	0.015	0.019	0.022	
z2	0.99	1.09	1.19	0.039	0.043	0.047	
θ	0°		5°	0°		5°	

ECN: C22-1223-Rev. C, 19-Dec-2022 DWG: 6067

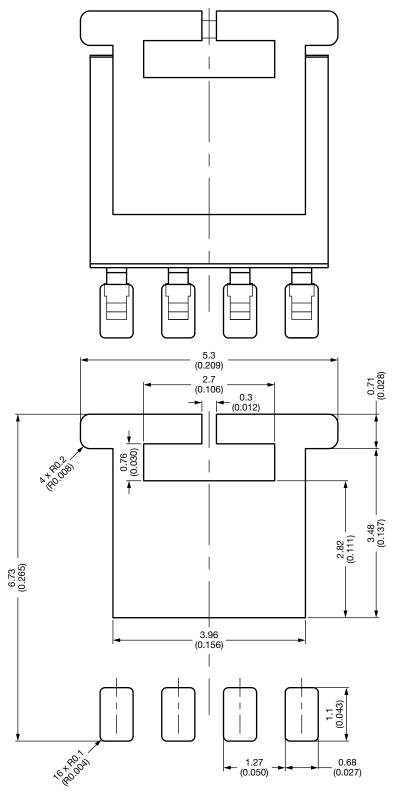
Note

Millimeter will govern

Revison: 19-Dec-2022 1 Document Number: 76666



Recommended Land Pattern PowerPAK® SO-8L Single Short Ear



Dimensions in Millimeters (Inches)



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